

Photointerrupter, General type



Absolute maximum ratings (Ta=25°C)

| Parameter                 |                             | Symbol           | Limits     | Unit   |
|---------------------------|-----------------------------|------------------|------------|--------|
| Input (LED)               | Forward current             | I <sub>F</sub>   | 50         | mA     |
|                           | Reverse voltage             | V <sub>R</sub>   | 5          | V      |
|                           | Power dissipation           | P <sub>D</sub>   | 80         | mW     |
| Output (photo-transistor) | Collector-emitter voltage   | V <sub>CEO</sub> | 30         | V      |
|                           | Emitter-collector voltage   | V <sub>ECO</sub> | 4.5        | V      |
|                           | Collector current           | I <sub>C</sub>   | 30         | mA     |
|                           | Collector power dissipation | P <sub>C</sub>   | 80         | mW     |
| Operating temperature     |                             | T <sub>opr</sub> | -25 to +85 | °C     |
| Storage temperature       |                             | T <sub>stg</sub> | -40 to +85 | °C     |
| Soldering temperture      |                             | T <sub>sol</sub> | 260 / 3 *  | °C / s |

\* 1mm from the body bottom.

Electrical and optical characteristics (Ta=25°C)

| Parameter                    |                                      | Symbol               | Min. | Typ. | Max. | Unit | Conditions                                                                                                                                     |
|------------------------------|--------------------------------------|----------------------|------|------|------|------|------------------------------------------------------------------------------------------------------------------------------------------------|
| Input charac-teristics       | Forward voltage                      | V <sub>F</sub>       | -    | 1.3  | 1.6  | V    | I <sub>F</sub> =50mA                                                                                                                           |
|                              | Reverse current                      | I <sub>R</sub>       | -    | -    | 10   | μA   | V <sub>R</sub> =10V                                                                                                                            |
| Output charac-teristics      | Dark current                         | I <sub>CEO</sub>     | -    | -    | 0.5  | μA   | V <sub>CE</sub> =10V                                                                                                                           |
|                              | Peak sensitivity wavelength          | λ <sub>P</sub>       | -    | 800  | -    | nm   | -                                                                                                                                              |
| Transfer characteristics     | Collector current                    | I <sub>C</sub>       | 0.5  | -    | -    | mA   | V <sub>CE</sub> =5V, I <sub>F</sub> =20mA                                                                                                      |
|                              | Collector-emitter saturation voltage | V <sub>CE(sat)</sub> | -    | 0.1  | 0.5  | V    | I <sub>F</sub> =20mA, I <sub>C</sub> =0.1mA                                                                                                    |
|                              | Response time                        | tr                   | -    | 10   | -    | μs   | V <sub>CC</sub> =5V, I <sub>F</sub> =20mA, R <sub>L</sub> =100Ω                                                                                |
| Infrared light emitter diode | Cut-off frequency                    | f <sub>C</sub>       | -    | 1    | -    | MHz  | I <sub>F</sub> =50mA                                                                                                                           |
|                              | Peak light emitting wavelength       | λ <sub>P</sub>       | -    | 950  | -    | nm   | * Non-coherent Infrared light emitting diode used.                                                                                             |
| Photo transistor             | Response time                        | tr•tf                | -    | 10   | -    | μs   | V <sub>CC</sub> =5V, I <sub>C</sub> =1mA, R <sub>L</sub> =100Ω<br>* This product is not designed to be protected against electromagnetic wave. |
|                              | Maximum sensitivity wavelength       | λ <sub>P</sub>       | -    | 800  | -    | nm   | -                                                                                                                                              |

Electrical and optical characteristics curves

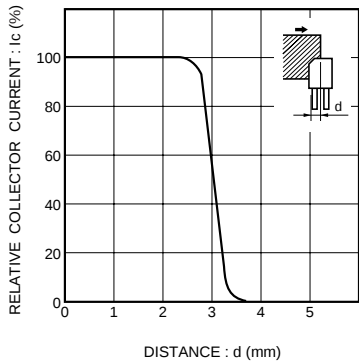


Fig.1 Relative output vs. distance (I)

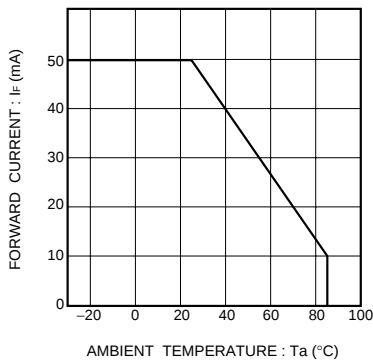


Fig.2 Forward current falloff

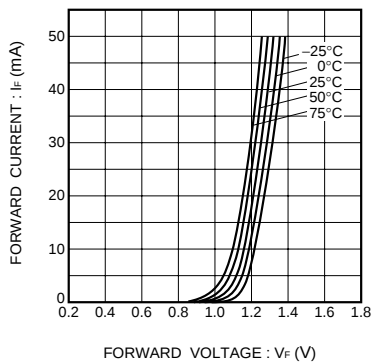


Fig.3 Forward current vs. forward voltage

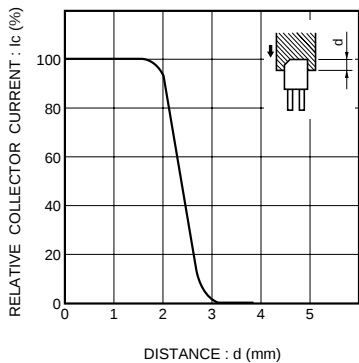


Fig.4 Relative output vs. distance (II)

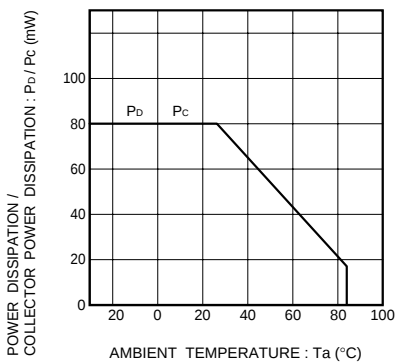


Fig.5 Power dissipation / collector power dissipation vs. ambient temperature

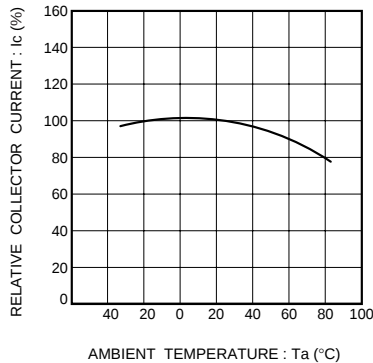
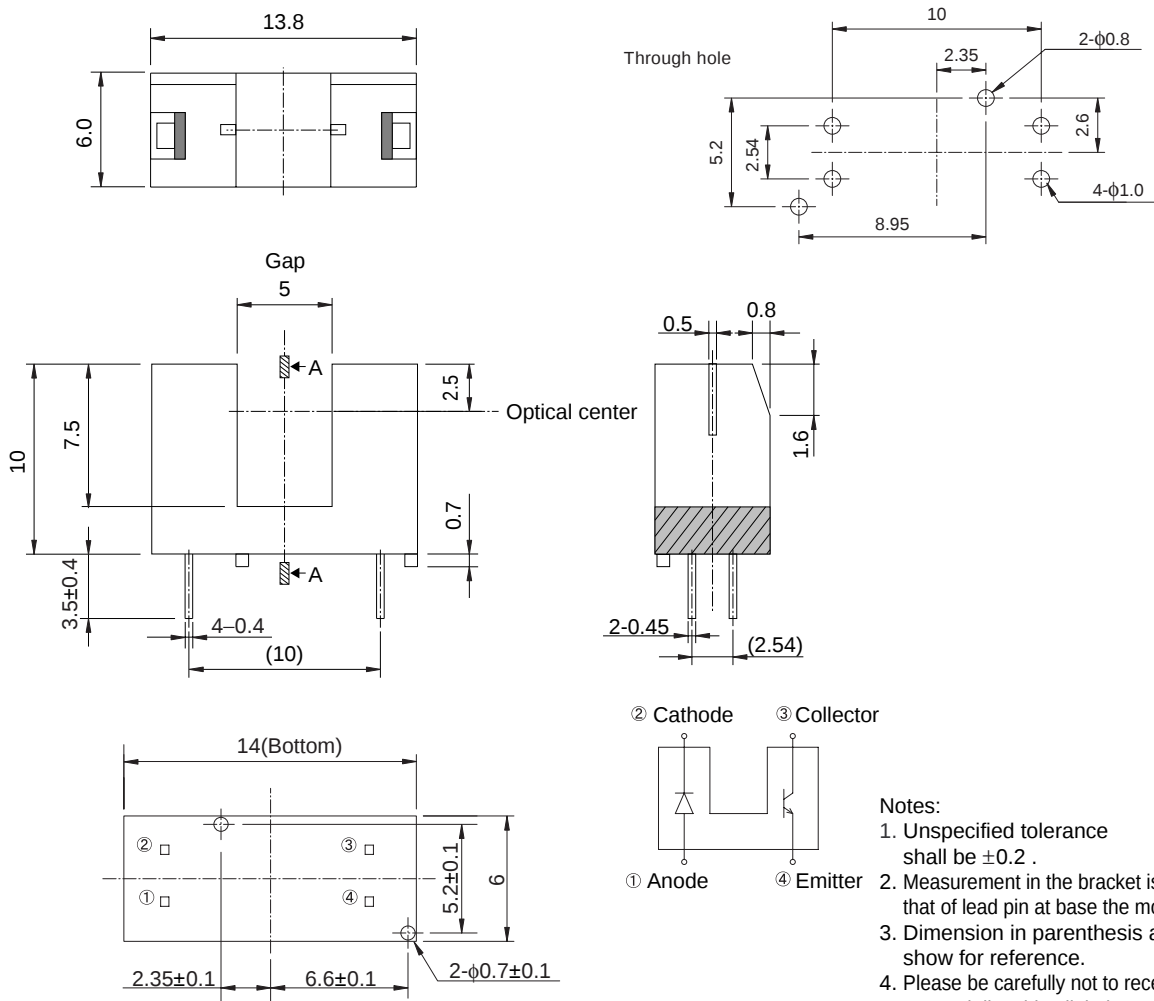


Fig.6 Relative output vs. ambient temperature

External dimensions (Unit : mm)



- Notes:
1. Unspecified tolerance shall be ±0.2 .
  2. Measurement in the bracket is that of lead pin at base the mold.
  3. Dimension in parenthesis are show for reference.
  4. Please be carefully not to receive external disturbing light because the top and back face emitter and detector element isn't covered by case.

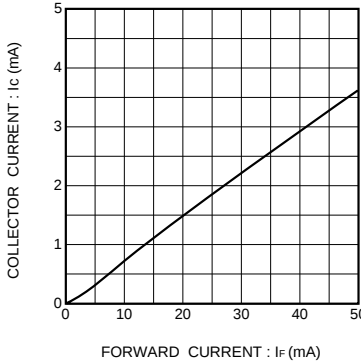


Fig.7 Collector current vs. forward current

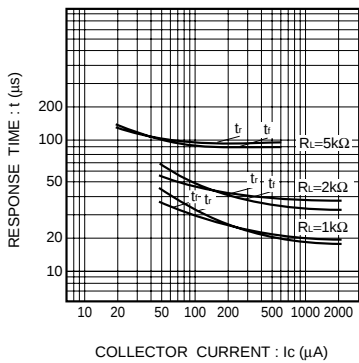


Fig.8 Response time vs. collector current

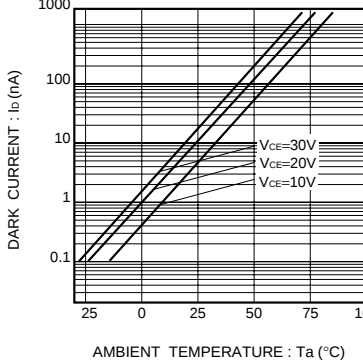


Fig.9 Dark current vs. ambient temperature

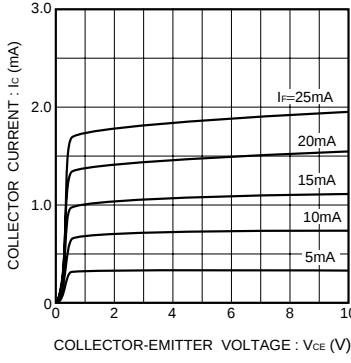
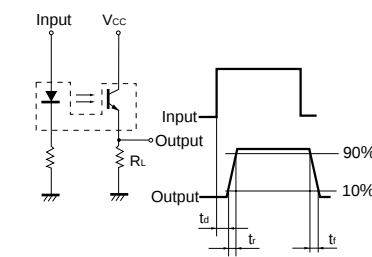


Fig.10 Output characteristics



t<sub>d</sub> : Delay time  
t<sub>r</sub> : Rise time (time for output current to rise from 10% to 90% of peak current)  
t<sub>f</sub> : Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.11 Response time measurement circuit

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